

**NPN Silicon Transistor** 

Ta=25°C

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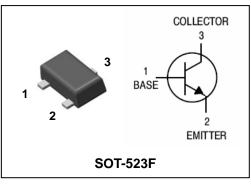
### Description

• General small signal amplifier

### Features

- Low collector saturation voltage : V<sub>CE(sat)</sub>=0.25V(Max.)
- Low output capacitance : C<sub>ob</sub>=2pF(Typ.)
- Complementary pair with 2SA1980EF

### **PIN Connection**



### **Ordering Information**

Type NO.	Marking	Package Code
2SC5343EF	<u>C</u> <u>□</u> <u>□</u> ① ② ③	SOT-523F

①Device Code ②hFE Rank ③Year&Week Code

### Absolute maximum ratings

			1u-20 C
Characteristic	Symbol	Ratings	Unit
Collector-Base voltage	V <sub>CBO</sub>	60	V
Collector-Emitter voltage	V <sub>CEO</sub>	50	V
Emitter-Base voltage	V <sub>EBO</sub>	5	V
Collector current	Ι <sub>C</sub>	150	mA
Collector dissipation	Pc	150	mW
Junction temperature	Tj	150	°C
Storage temperature	T <sub>stg</sub>	-55~150	°C

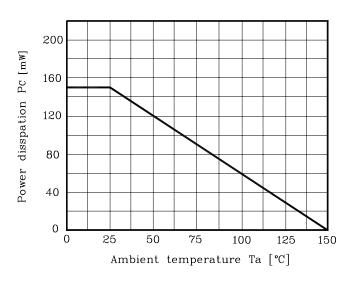
### **Electrical Characteristics**

Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Collector-Base breakdown voltage	$BV_{CBO}$	$I_{C} = 100 \mu A, I_{E} = 0$	60	-	-	V
Collector-Emitter breakdown voltage	BV <sub>CEO</sub>	$I_{C}=1mA$ , $I_{B}=0$	50	-	-	V
Emitter-Base breakdown voltage	BV <sub>EBO</sub>	$I_{E} = 10 \mu A$ , $I_{C} = 0$	5	-	-	V
Collector cut-off current	I <sub>CBO</sub>	$V_{CB} = 60V$ , $I_{E} = 0$	-	-	0.1	μA
Emitter cut-off current	I <sub>EBO</sub>	$V_{EB}$ =5V, $I_{C}$ =0	-	-	0.1	μA
DC current gain	h <sub>FE</sub> *	$V_{CE}$ =6V, $I_{C}$ =2mA	70	-	700	-
Collector-Emitter saturation voltage	V <sub>CE(sat)</sub>	$I_{C}$ =100mA, $I_{B}$ =10mA	-	-	0.25	V
Transistion frequency	f <sub>T</sub>	$V_{CE}$ =10V, $I_{C}$ =1mA	80	-	-	MHz
Collector output capacitance	C <sub>ob</sub>	$V_{CB}$ =10V, $I_{E}$ =0, f=1MHz	-	2	3.5	pF
Noise figure	NF	V <sub>CE</sub> =6V, I <sub>C</sub> =0.1mA, f=1KHz, Rg=10KΩ	-	-	10	dB

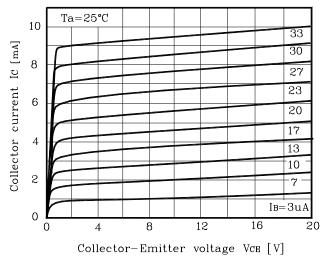
\* : h\_{FE} rank / O : 70 ~ 140, Y : 120 ~ 240, G : 200 ~ 400, L : 300 ~ 700

### **Electrical Characteristic Curves**

#### Fig. 1 P<sub>C</sub> –T<sub>a</sub>









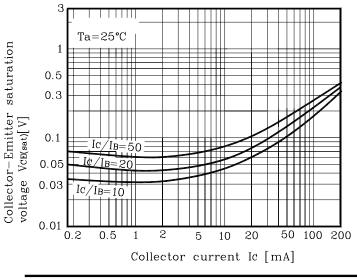


Fig. 2  $I_C$  -V<sub>BE</sub>

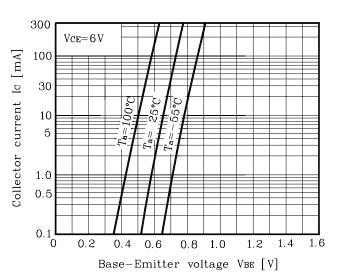
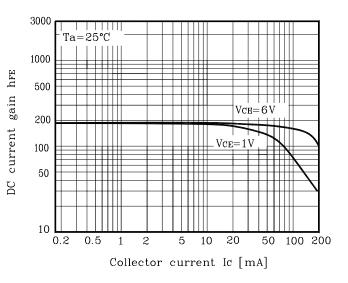
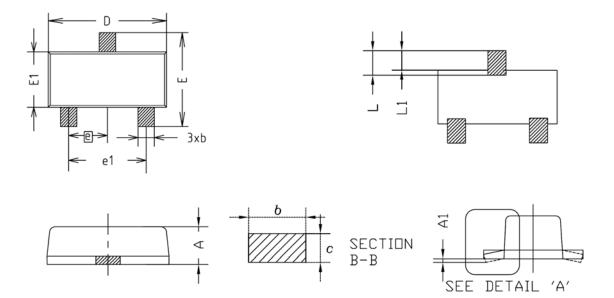


Fig. 4 h<sub>FE</sub> -I<sub>C</sub>



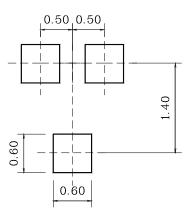
KSD-T5E006-000

### **Outline Dimension**



SYMBOL	MILLIMETERS			NOTE
STHELL	MINIMUM	NOMINAL	MAXIMUM	NUTE
Α	0.63	0.68	0.73	
A1	0.00	-	0.10	
A2	-	-	-	
b	0.25	0.30	0.35	
С	0.04	0.11	0.20	
D	1.50	1.60	1.70	
E	1.50	1.60	1.70	
E1	0.78	0.88	0.98	
e	0.50BSC			
e1	0.90	-	1.10	
L	0.34	0.44	0.54	
L1	0.28	0.34	0.43	

\*Recommend PCB solder land [Unit: mm]



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